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APPLICATION NO.	FI	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/848,846	09/848,846 05/03/2001		Luan C. Tran	MI22-1689 1789	
21567	7590	11/02/2004	EXAMINER		INER
WELLS ST			SCHILLINGER, LAURA M		
601 W. FIRST AVENUE, SUITE 1300 SPOKANE, WA 99201				ART UNIT	PAPER NUMBER

2813

DATE MAILED: 11/02/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
Office Action Summany	09/848,846	TRAN, LUAN C.				
Office Action Summary	Examiner	Art Unit				
	Laura M Schillinger	2813				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repless of the period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tir ly within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. C) (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 02 A	August 2004.					
·	·					
* * * * * * * * * * * * * * * * * * * *	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) Claim(s) 11,12 and 14 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 11,12 and 14 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9) The specification is objected to by the Examin 10) The drawing(s) filed on is/are: a) accomposite and applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examin	cepted or b) objected to by the drawing(s) be held in abeyance. Section is required if the drawing(s) is ob	e 37 CFR 1.85(a). ojected to. See 37 CFR 1.121(d).				
Priority under 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
Attachment(s)						
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date	4) Interview Summar Paper No(s)/Mail D 5) Notice of Informal 6) Other:					

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DETAILED ACTION

Allowability of claims 11-12 and 14 is withdrawn in view of the newly discovered reference.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 11-12 and 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lowrey et al ('504).

In reference to claim 11, Lowrey teaches a semiconductor processing method comprising: a masking step providing a common mask; and an implant step carried out through the common mask, comprising conducting a halo implant of devices formed over a substrate comprising memory circuitry and peripheral circuitry sufficient to impart to at least two of the devices two different respective threshold voltages, wherein the common masking step comprises masking only portions of some of the devices which receive the halo implant, said portions comprising portions of peripheral circuitry devices (Fig. 6 and Col. 6, lines: 60-65; see also Col. 2, lines: 1-20).

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In reference to claim 12, Lowrey teaches a semiconductor processing method comprising:

a masking step providing a common mask (Col.2, lines: 1-20); and an implant step carried out through the common mask, comprising conducting a halo implant of devices formed over a substrate comprising memory circuitry and peripheral circuitry sufficient to impart to at least two of the devices two different respective threshold voltages, wherein the common masking step comprises masking only portions of some of the devices which receive the halo implant, said devices which receive the halo implant comprise NMOS field effect transistors; and said portions comprise portions of peripheral circuitry devices (Col.2, lines: 1-20 and Col.6, lines: 60-65 and Fig.6).

In reference to claim 14, Lowrey teaches a semiconductor processing method comprising:

a masking step providing a common mask; and an implant step carried out through the common mask, comprising conducting a halo implant of devices formed over a substrate comprising memory circuitry and peripheral circuitry sufficient to impart to at least two of the devices two different respective threshold voltages, wherein the common masking step comprises masking only portions of some of the devices which receive the halo implant', said devices which receive the halo implant comprise PMOS field effect transistors', and said portions comprise portions of peripheral circuitry devices (Col.2, lines: 1-20 and Fig.6 and Col.6, lines: 60-65).

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However with respect claims 11-12 and 14, Lowrey fails to teach three different transistors having three different threshold voltages. However, the courts have held that mere duplication of parts has no patentable significance unless a new or unexpected result is produced see In re Harza, 274 F.2d 669, 124 USPQ 378 (CCPA 1960). Therefore Applicant's claim language is considered to be an obvious variation of Lowrey's teachings.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Laura M Schillinger whose telephone number is (571) 272-1697. The examiner can normally be reached on M-T, R-F 7:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl W Whitehead, Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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LMS

10/31/04